..

**Example 1.1:** A silicon diode has a reverse saturation current of 7.12 nA at room temperature of 27 °C. Calculate its forward current if it is forward biased with a voltage of 0.7 V.

solution: The given values are,  $I_0 = 7.12 \text{ nA} = 7.12 \times 10^{-9} \text{ A}$ , V = + 0.7 V as forward biased.

 $\eta = 2$  for silicon diode,  $T = 27 \, ^{\circ}\text{C} = 27 + 273 = 300 \, ^{\circ}\text{K}$ 

Now  $V_T = kT = 8.62 \times 10^{-5} \times 300 = 0.026 \text{ V}$ 

According to diode current equation,

I = I<sub>0</sub> (
$$e^{V/\eta V_T} - 1$$
)  
I =  $7.12 \times 10^{-9} (e^{0.7/2 \times 0.026} - 1)$   
=  $7.12 \times 10^{-9}$  [701894.59 - 1] =  $4.99 \times 10^{-3}$  A  $\approx 5$  mA

Thus the forward current is 5 mA

**Example 1.2**: The voltage across a silicon diode at room temperature of 300 °K is 0.71 V when 2.5 mA current flows through it. If the voltage increases to 0.8 V, calculate the new diode current.

Solution: The current equation of a diode is

$$I = I_0 (e^{V/\eta V_T} - 1)$$

At 300 °K, 
$$V_T = 26 \text{ mV} = 26 \times 10^{-3} \text{ V}$$

$$V = 0.71 \text{ V for } I = 2.5 \text{ mA}$$
 and  $\eta = 2 \text{ for silicon}$ 

$$2.5 \times 10^{-3} = I_0 [e^{(0.71/2 \times 26 \times 10^{-3})} - 1]$$

$$I_0 = 2.93 \times 10^{-9} \text{ A}$$

Now V = 0.8 V

I = 
$$2.93 \times 10^{-9} [e^{(0.8/2 \times 26 \times 10^{-3})} - 1]$$
  
=  $0.0141 A = 14.11 mA$ 

**Example 2.1**: A half wave rectifier circuit is supplied from a 230 V, 50 Hz supply with a step down ratio of 3:1 to a resistive load of 10 k $\Omega$ . The diode forward resistance is 75  $\Omega$  while transformer secondary resistance is 10  $\Omega$ . Calculate maximum, average, RMS values of current, D.C. output voltage, efficiency of rectification and ripple factor.

**Solution**: The circuit is shown in the Fig. 2.8.

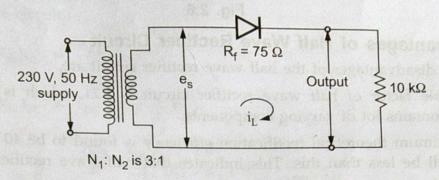


Fig. 2.8

The given values are,

$$R_{\rm f} = 75~\Omega,~R_{\rm L} = 10~k\Omega,~R_{\rm s} = 10~\Omega.$$

 $E_s(R.M.S.) = 76.667 V$ 

The given supply voltages are always r.m.s. values.

$$E_{p}(R.M.S.) = 230 \text{ V}, \quad \frac{N_{1}}{N_{2}} = \frac{3}{1} \text{ i.e. } \frac{N_{2}}{N_{1}} = \frac{1}{3}$$

$$\frac{N_{2}}{N_{1}} = \frac{E_{s}(R.M.S.)}{E_{p}(R.M.S.)}$$

$$\therefore \qquad \frac{1}{3} = \frac{E_{s}(R.M.S.)}{230}$$

This is r.m.s. value of the transformer secondary voltage.

$$\vdots \qquad E_{sm} = \sqrt{2} E_s(R.M.S.) = \sqrt{2} \times 76.667 = 108.423 \text{ V}$$

$$\vdots \qquad I_m = \frac{E_{sm}}{R_s + R_f + R_L} = \frac{108.423}{10 + 75 + 10 \times 10^3}$$

$$= 10.75 \text{ mA}$$

$$\begin{split} I_{av} &= I_{DC} = \frac{I_m}{\pi} = \frac{10.75}{\pi} = \textbf{3.422 mA} \\ I_{RMS} &= \frac{I_m}{2} \quad \text{for half wave} \\ &= \frac{10.75}{2} = \textbf{5.375 mA} \\ E_{DC} &= \text{d.c output voltage} = I_{DC} R_L \\ &= 3.422 \times 10^{-3} \times 10 \times 10^3 = \textbf{34.22 V} \\ P_{DC} &= \text{d.c. output power} = E_{DC} I_{DC} = 34.22 \times 3.422 \times 10^{-3} \\ &= 0.1171 \ W \end{split}$$

This also can be obtained as,

$$P_{DC} = \frac{I_{m}^{2}}{\pi^{2}} R_{L}^{*} = \frac{\left(1075 \times 10^{-3}\right)^{2}}{\pi^{2}} \times 10 \times 10^{3}$$

$$= 0.1171 \text{ W}$$

$$P_{AC} = \text{a.c. input power} = I_{RMS}^{2} \left[R_{s} + R_{f} + R_{L}\right]$$

$$= \left(5.375 \times 10^{-3}\right)^{2} \left[10 + 75 + 10 \times 10^{3}\right] = 0.2913 \text{ W}$$

$$\% \eta = \frac{P_{DC}}{P_{AC}} \times 100 = \frac{0.1171}{0.2913} \times 100 = 40.19 \%$$

The ripple factor is constant for half wave rectifier and is 1.21.

$$\therefore \qquad \qquad \gamma = 1.21$$

**Example 2.3**: A voltage  $V = 300 \cos 100$  t is applied to a half wave rectifier, with  $R_L = 5 \text{ k}\Omega$ . The rectifier may be represented by ideal diode in series with a resistance of  $1 \text{ k}\Omega$ . Calculate

i)  $I_m$  ii) D.C. power iii) A.C. power iv) Rectifier efficiency and v) Ripple factor.

Solution: The diode circuit is as shown in the Fig. 2.10.

The given voltage is  $V = 300 \cos 100 t$  volts

Compare with,  $E = E_{sm} \sin \omega t$ 

$$E_{sm} = 300 \text{ volts}$$

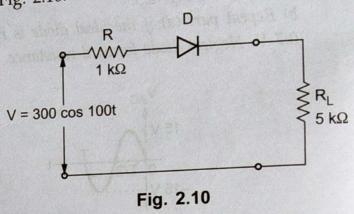
 $R = 1 \text{ k}\Omega$  = Resistance in series with diode

$$R_L = 5 \text{ k}\Omega$$
,  $R_s = R_f = 0 \Omega$ 

i) 
$$I_{\rm m} = \frac{E_{\rm sm}}{R + R_{\rm L} + R_{\rm f} + R_{\rm L}} = \frac{300}{6 \times 10^3}$$

$$=$$
 50 mA.

ii) 
$$I_{DC} = \frac{I_m}{\pi} = \frac{50}{\pi} = 15.9154 \text{ mA}$$



$$P_{DC} = I_{DC}^{2}R_{L} = (15.9154 \times 10^{-3})^{2} \times 5 \times 10^{3}$$

$$= 1.2665 \text{ watts}$$

iii) 
$$\begin{split} P_{AC} &= I_{RMS}^2 \; (R + R_L + R_s + R_f) \\ &= \left(\frac{I_m}{2}\right)^2 (R + R_L + R_s + R_f) \; \text{ as } I_{RMS} = \frac{I_m}{2} \; \text{for half wave} \\ &= \left(\frac{50 \times 10^{-3}}{2}\right)^2 \times 6 \times 10^3 = \textbf{3.75 watts} \end{split}$$

iv) 
$$\eta = \frac{P_{DC}}{P_{AC}} \times 100 = \frac{1.2665}{3.75} \times 100$$
$$= 33.77 \%$$

v) Ripple factor = 
$$\sqrt{\left(\frac{I_{RMS}}{I_{DC}}\right)^2 - 1} = \sqrt{\left(\frac{25 \times 10^{-3}}{15.9154 \times 10^{-3}}\right)^2 - 1}$$
  
= 1.211

- **Example 2.4**: A half wave rectifier circuit connected to a 230 V, 50 Hz source, through a transformer of turn ratio of 10:1. The rectifier circuit is to supply power to a 500  $\Omega$ , 1 watt resistor and diode forward resistance is 100  $\Omega$ .

  Calculate:
  - 1) Maximum, average and r.m.s. value of current and voltage.
  - 2) Efficiency of rectification.
  - 3) Percentage regulation.

Solution : 
$$E_{p \text{ (r.m.s.)}} = 230 \text{ V}, N_1/N_2 = 10:1, R_L = 500 \Omega, R_f = 100 \Omega$$
 
$$\frac{N_2}{N_1} = \frac{1}{10} = \frac{E_{s \text{ (r.m.s.)}}}{E_{p \text{ (r.m.s.)}}}$$

$$E_{s (r.m.s.)} = \frac{1}{10} \times 230 = 23 \text{ V}$$

$$E_{sm} = \sqrt{2} \times E_{s(r.m.s.)} = \sqrt{2} \times 23 = 32.5269 \text{ V}.$$

1) : 
$$I_m = \frac{E_{sm}}{R_f + R_L} = \frac{32.5269}{100 + 500} = 54.2115 \text{ mA}$$

... Maximum current

$$I_{av} = I_{DC} = \frac{I_m}{\pi} = 17.2561 \text{ mA}$$

$$I_{R.M.S.} = \frac{I_m}{2}$$
 for half wave = 27.1058 mA

$$E_{DC} = I_{DC}R_{L} = 8.628 \text{ V}$$

$$P_{DC} = I_{DC}^{2}R_{L} = 0.14888 \text{ W}$$

$$P_{AC} = I_{RMS}^{2}(R_{L} + R_{f}) = 0.44083 \text{ W}$$

$$\therefore \qquad \% \eta = \frac{P_{DC}}{P_{AC}} \times 100 = \frac{0.14888}{0.44083} \times 100 = 33.7723 \%$$

$$(V_{d.c.})_{NL} = \frac{E_{sm}}{\pi} = \frac{32.5269}{\pi} = 10.3536 \text{ V}$$

$$(V_{d.c.})_{L} = E_{DC} = 8.628 \text{ V}$$

$$\therefore \qquad \% R = \frac{(V_{dc})_{NL} - (V_{dc})_{L}}{(V_{dc})_{L}} \times 100 = 20 \%$$

Example 2.5: In a centre-tapped full wave rectifier, the rms half secondary voltage is 9 V. Assuming ideal diodes and load resistance  $R_L = 1 \text{ k}\Omega$ , find:

i) Peak current ii) D.C. load voltage iii) R.M.S. current iv) Ripple factor v) Efficiency.

Solution : 
$$E_s(r.m.s.) = 9 \ V, \ R_L = 1 \ k\Omega$$

$$I_{\rm m} = \frac{E_{\rm sm}}{R_{\rm L}}$$

Now 
$$E_{sm} = \sqrt{2}E_s(r.m.s.) = \sqrt{2} \times 9 = 12.7279 \text{ V}$$

:. 
$$I_{\rm m} = \frac{12.7279}{1 \times 10^3} = 12.7279 \text{ mA}$$
 ... Peak current

ii) 
$$I_{DC} = \frac{2I_m}{\pi} = \frac{2 \times 12.7279}{\pi} = 8.1028 \text{ mA}$$

$$E_{DC} = I_{DC}R_{L} = 8.1028 \times 10^{-3} \times 1 \times 10^{3} = 8.1028 \text{ V}$$

iii) 
$$I_{RMS} = \frac{I_m}{\sqrt{2}} = \frac{12.7279}{\sqrt{2}} = 9 \text{ mA}$$

iv) Ripple factor = 
$$\sqrt{\left[\frac{I_{RMS}}{I_{DC}}\right]^2 - 1} = \sqrt{\left(\frac{9}{8.1028}\right)^2 - 1}$$

$$= 0.48$$

$$P_{DC} = I_{DC}^2 R_L = (8.1028)^2 \times 1 \times 10^3 = 65.65 \text{ mW}$$

$$P_{AC} = I_{RMS}^2 R_L = (9)^2 \times 1 \times 10^3 = 81 \text{ mW}$$

$$\therefore \qquad \% \ \eta \ = \ \frac{P_{DC}}{P_{AC}} \times 100 = \frac{65.65}{81} \times 100 = 81.04 \%$$

**Example 2.9:** The four semiconductor diodes used in a bridge rectifier circuit each having a forward resistance of 0.1  $\Omega$  and infinite reverse resistance, feed a d.c. current of 10 A to a resistive load from a sinusoidally varying alternating supply of 30 V (r.m.s). Determine the resistance of the load and the efficiency of the circuit.

Solution: The given values are,

$$R_{f} = 0.1 \ \Omega \ , \ I_{DC} = 10 A, \ R_{s} = 0 \ \Omega \ , \ E_{s}(R.M.S.) = 30 \ V$$

$$E_{sm} = E_{sm}(R.M.S.) \times \sqrt{2} = \sqrt{2} \times 30$$

$$= 42.4264 \ V$$

$$I_{DC} = \frac{2I_{m}}{\pi}$$

$$I_{m} = \frac{\pi \times I_{DC}}{2} = \frac{\pi \times 10}{2} = 15.7079 \ A$$

Now 
$$I_{m} = \frac{E_{sm}}{2R_{f} + R_{s} + R_{L}}$$

$$\therefore 15.7079 = \frac{42.4264}{2 \times 0.1 + R_{L}}$$

$$\therefore R_{L} + 0.2 = 2.7$$

$$\therefore R_{L} = 2.5 \Omega$$
Now 
$$P_{DC} = I_{DC}^{2}R_{L} = (10^{2}) \times 25 = 250 \text{ W}$$

$$P_{AC} = I_{RMS}^{2}(2R_{f} + R_{s} + R_{L})$$
and 
$$I_{RMS} = \frac{I_{m}}{\sqrt{2}} = \frac{15.7079}{\sqrt{2}} = 11.1071 \text{ A}$$

$$\therefore P_{AC} = (11.1071)^{2} [2 \times 0.1 + 2.5] = 333.092 \text{ W}$$

$$\therefore \% \eta = \frac{P_{DC}}{P_{AC}} \times 100$$

$$= \frac{250}{333.092} \times 100$$

$$= 75.05 \% \dots \text{ Rectifier efficiency}$$

## = 0.28 V

**Example 2.39:** A 230 V, 60 Hz voltage is applied to the primary of a 5: 1 step  $d_{0wn}$ , former used in the full wave rectifier having a load of 900  $\Omega$ . If the same **Example 2.39**: A 230 V, 60 Hz totals wave rectifier having a load of 900  $\Omega$ . If the down, center tapped transformer used in the full wave rectifier having a load of 900  $\Omega$ . If the dode center tapped transformer used in the full wave rectifier having a load of 900  $\Omega$ . If the dode center tapped transformer used in the full wave rectifier having a load of 900  $\Omega$ . If the dode center tapped transformer used in the full wave rectifier having a load of 900  $\Omega$ . If the dode center tapped transformer used in the full wave rectifier having a load of 900  $\Omega$ , determine center tapped transformer used in the junction together has a resistance of  $100 \Omega$ ,  $\frac{\Omega}{100} = \frac{100 \Omega}{100 \Omega}$ ,  $\frac{\Omega}{100 \Omega} = \frac{100 \Omega}{100 \Omega}$ , determine ii) d.c. current flowing through the load

- i) d.c. voltage across the load
- iii) d.c. power delivered to the load
- v) ripple voltage and its frequency.

iv) PIV across each diode

JNTU: May-2003, Set-1; May - 2004, Set-4; June-2009, Set-1, 2

## Solution :

..

$$\frac{N_2}{N_1} = \frac{2E_{s (rms)}}{E_{p (rms)}}$$

$$\dots E_{p(rms)} = 230 \text{ V}$$

$$\therefore \qquad \frac{1}{5} = \frac{2 E_{s (rms)}}{230}$$

$$E_{s(rms)} = 23 \text{ V (each half)}$$

$$R_L = 900 \Omega$$

$$R_s + R_f = 100 \ \Omega$$

$$I_{m} = \frac{E_{sm}}{R_{L} + R_{s} + R_{f}}$$

$$= \frac{\sqrt{2} \times E_{s \text{ (rms)}}}{R_L + R_s + R_f} = \frac{\sqrt{2} \times 23}{900 + 100} = 0.03252 \text{ A}$$

$$I_{DC} = \frac{2I_{m}}{\pi} = \frac{2 \times 0.03252}{\pi} = 0.0207 \text{ A}$$

i) 
$$E_{DC} = I_{DC} R_L = 0.0207 \times 900 = 18.6365 V$$

ii) 
$$I_{DC} = 0.0207 A$$

iii) 
$$P_{DC} = I_{DC}^2 R_L \text{ or } E_{DC} \times I_{DC} = 0.3857 \text{ W}$$

iv) PIV = 
$$2 E_{sm} = 2 \times \sqrt{2} \times 23 = 65.0538 \text{ V}$$

v) Ripple factor = 
$$0.482 = \frac{V_{r \text{ (rms)}}}{E_{DC}}$$

: Ripple voltage = 
$$V_{r(rms)} = 0.482 \times 18.6365 = 8.9827 \text{ V}$$

Frequency of ripple = 
$$2f = 2 \times 60 = 120 \text{ Hz}$$

**Example 2.40**: In a bridge rectifier the transformer is connected to 220 V, 60 Hz mains and the turns ratio of the step down transformer is 11: 1. Assuming the diode to be ideal, find:

i)  $I_{DC}$  ii) voltage acorss the load iii) PIV.

Assume load resistance to be  $1 k\Omega$ 

JNTU: May-2003, Set-3

Solution:  $\frac{N_2}{N_1} = \frac{1}{11}$ ,  $E_{p(rms)} = 220 \text{ V}$ , f = 60 Hz,  $R_L = 1 \text{ k}\Omega$   $\frac{N_2}{N_1} = \frac{E_{s \text{ (rms)}}}{E_{p \text{ (rms)}}}$ 

Peak Invesse voltage (PIV) (6) peak Revesse voltage (PRV):

PIV refer to the maximum voltage a diode of an with stand in the sevesse—biased disention before Breakdown.

PIV Center tapped FWR -> 2Vm

Bridge Retlifiers -> Vm

+ there -> Vm